Electronic Supplementary Information

Rational design of Sn-based multicomponent anodes for

high performance lithium-ion batteries:

SnO2@TiO2@reduced graphene oxide nanotubes

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Experimental

Synthesis of materials

For the electrospinning solution of $SnO₂$ nanotubes (NTs), 1 g of tin chloride dehydrate (SnCl₂ ²H₂O, Sigma Aldrich), 5 g of ethanol (C₂H₆O, Merck) were mixed first and stirred for 2 h and 1.4 g of polyvinylpyrrolidone (M_w = 1,300,000, PVP, Sigma Aldrich) and 5 g of N, N-dimethylformamide (DMF, Sigma Aldrich) were added and stirred for 4 h. Electrospinning was conducted under the following conditions: distance of 12 cm between the tip of the needle (25 gauge) and current collector, applied voltage of 15 kV, with a flow rate of 20μ l min⁻¹. As-spun Sn precursor/PVP nanofibers (NFs), then, were calcined at 600 °C for 1 h and 700 °C for 1 h at a heating rate of 10 °C min⁻¹ in a muffle furnace under air atmosphere, in order that $SnO₂ NTs$ were formed. To carry out the sol-gel process of $TiO₂$ layer on top of $SnO₂ NTs$, 0.12 g of titanium butoxide $(Ti[O(CH₂)₃CH₃]₄$, Aldrich) and 0.12 g of de-ionized water (DIW) were mixed in 4.8 g of ethylene glycol (EG, Junsei Chemical) and 1.2 g of ethanol in the presence of 0.3 g of $SnO₂$ for 6 h at 80 °C. It was cleaned with ethanol two times by centrifugation at 3000 rpm for 15 min each. It was dried overnight (for 12 h) and thermally annealed at 550 °C for 1 h at a heating rate of 10 °C min-1 in a muffle furnace under air atmosphere. This sample is denoted as $SnO₂(Q)TiO₂$. For another sample with higher $TiO₂$ concentration, 0.4 g of titanium butoxide $(Ti[O(CH₂)₃CH₃]₄$, Aldrich) and 0.4 g of DIW were mixed in 3.2 g of ethylene glycol (EG, Junsei Chemical) and 0.8 g of ethanol in the presence of 0.2 g of $SnO₂$ for 6 h at 80 °C, under same centrifugation condition and subsequent drying and annealing process. This sample is denoted as $\text{SnO}_2(\partial T_1)$ (X5). To synthesize $\text{SnO}_2(\partial T_1)$ NTs wrapped by rGO sheets, 0.3 g of $\text{SnO}_2(\partial T_1)$ was mixed with 0.1 g of polyallylamine hydrochloride (PAH, $M_w = 15,000$, Sigma Aldrich) for 2 h and centrifuged three times at 3000 rpm for 15 min each. It was dried for 12 h and stirred with 6 g of graphene oxide in

water solution (2 ml mg⁻¹, Sigma Aldrich) for 24 h. It was then mixed and stirred with 2 g of hydrazine monohydrate (64–65%, Sigma Aldrich) and dried for 12 h. This rGO-wrapped $SnO₂(Q)TiO₂$ sample is denoted as $SnO₂(*a*)TiO₂(*a*)rGO.$

Cell Assembly

To carry out the electrochemical tests, cells were assembled in 2032 coin-type half cells. The anodes $(SnO_2, SnO_2(\partial TiO_2, and SnO_2(\partial TiO_2(\partial TiO_2 \partial TiO_2)))$ were composed of active materials, super P carbon black, poly(acrylic acid)/sodium carboxymethyl cellulose (50/50 wt%/wt%, Aldrich) binder at a weight ratio of 80:10:10. They were slurry-casted on Cu current collector and dried in a vacuum at 150 °C for 2 h. The mass loading of active materials were \sim 2 mg cm⁻² for SnO₂, SnO₂@TiO₂, and SnO₂@TiO₂@rGO NTs. The 2032 coin-type half cells consisted of lithium metal as a counter electrode, a Celgard 2325 separator, and 1.3 M lithium hexafluorophosphate $(LiPF_6)$ in ethylene carbonate/diethylene carbonate (EC/DEC, $3/7$ v/v) with 10 wt% fluoroethylene carbonate (FEC) (PANAX ETEC.) for electrolytes. They were assembled in an Ar-filled glove box.

Characterization

As-spun Sn precursor/PVP NFs, $SnO₂$, $SnO₂(Q)TiO₂$, and $SnO₂(Q)TiO₂(Q)TGO$ NTs were characterized by a field emission scanning electron microscopy (FE-SEM, Nova 230, FEI) operating at 10 kV. Surface area of $SnO₂(Q)TiO₂$ was measured using BET (Brunauer–Emmett–Teller) device (Tristar II 3020, Micromeritics). To characterize the morphologies of the $SnO₂(QTiO₂)$ $\text{SnO}_2(\partial T_1O_2(X5))$, and $\text{SnO}_2(\partial T_1O_2(\partial T_2O))$, field emission electron microscopy (FE-TEM, Tecnai TF30 ST, FEI) operating at 300 kV was employed. The crystalline structure of $SnO₂$ and $SnO₂(Q)TiO₂(X5)$ was analyzed with a powder

X-ray diffractometer (XRD, D/MAX-2500, Rigaku) using Cu K α radiation $(\lambda=1.54 \text{ Å})$ between 20° and 80° at a scan rate of 0.066 ° s⁻¹. The weight percentage of rGO in $SnO_2(aTiO_2(a)rGO)$ was confirmed by thermogravimetry analyzer (TGA, TG 209 F3, NETZSCH). Raman spectra were obtained from dispersive Raman spectrometer (ARAMIS, Horiba Jobin Yvon) to investigate the characteristics of wrapped rGO layer in $SnO₂(Q)TiO₂(Q)IGO$ using a He-Ne laser operating at $\lambda = 633$ nm. Surface state of SnO₂@TiO₂ and $SnO₂(Q)TiO₂(Q)FGO$ was analyzed using X-ray photoelectron spectroscopy (XPS) (K-alpha, Thermo VG Scientific). The 2032 coin-type half cells were cycled at a current density of 100-5000 mA g⁻¹ between 0.01 and 3 V using battery testing device (Maccor Series 4000, KOREA THERMO-TECH). Cyclic voltammetry (CV) was conducted at 0.1 mV s^{-1} within a range of 0.01 to 3.0 V using battery testing device (WBCS4000, Wonatech). Conductivity of $SnO₂$, $SnO₂(QTiO₂)$, and $\text{SnO}_2(\partial T_1\text{O}_2(\partial T_2\text{O}))$ NTs was examined by an AC impedance analyzer (ZIVE SP1, Wonatech).

Fig. S1 XRD patterns of SnO₂ NTs.

Fig. S2 (a) Nitrogen adsorption-desorption isotherms and (b) pore size distribution of $SnO_2@TiO_2 NTs$.

Fig. S3 (a) TEM image of $\text{SnO}_2(\widehat{a})$ TiO₂ (X5) NTs in low magnification, (b) TEM image magnified from the red box seen in (a) confirming the crystal structure of TiO₂, (c) SAED pattern of $SnO₂(QTiO₂ (X5) NTs$ showing both the crystal structure of $SnO₂$ (yellow) and $TiO₂$ (green), and (d) XRD patterns of $SnO₂(\emptyset)TiO₂(\times 5) NTs.$

Fig. S4 Cyclic voltammetry (CV) curve of $SnO_2@TiO_2$ NTs, from 1st to 3rd cycle, at a scan rate of 0.1 mV s^{-1} between 0.01 and 3 V .

Fig. S5 Cycle retention of SnO² NTs under different calcination conditions at a current density 500 mA g^{-1} between 0.01 and 3 V.

Fig. S6 Charge/discharge profile of $SnO_2@TiO_2$ NTs at a current density of 500 mA g^{-1} between 0.01 and 3 V.

Fig. S7 SEM image of (a) SnO_2 , (b) SnO_2 @TiO₂, and (c) SnO_2 @TiO₂@rGO electrodes after 50 cycles at 500 mA g⁻¹. Insets are magnified SEM images showing the surface of SnO_2 , $SnO_2@TiO_2$, and $SnO_2@TiO_2@rGO$. Scale bars in the insets are 500 nm.

Fig. S8 Nyquist plots of three different samples $(SnO_2@TiO_2@rGO,$ $SnO_2@TiO_2$, and $SnO_2 NTs$) after 50th cycle at a current density of 500 mA g⁻¹.